

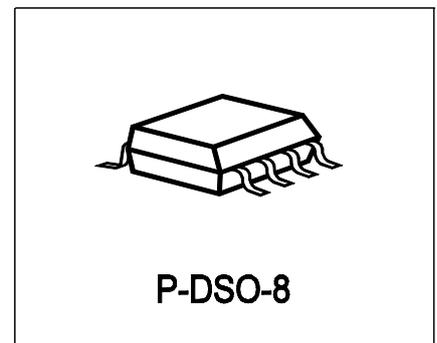
Smart Power High-Side-Switch

Features

- Overload protection
- Current limitation
- Short circuit protection
- Thermal shutdown with restart
- Overvoltage protection (including load dump)
- Fast demagnetization of inductive loads
- Reverse battery protection with external resistor
- CMOS compatible input
- Loss of GND and loss of V_{bb} protection
- ESD - Protection
- Very low standby current

Product Summary

Overvoltage protection	$V_{bb(AZ)}$	62	V
Operating voltage	$V_{bb(on)}$	6...52	V
On-state resistance	R_{ON}	200	m Ω
Nominal load current	$I_{L(nom)}$	1.3	A



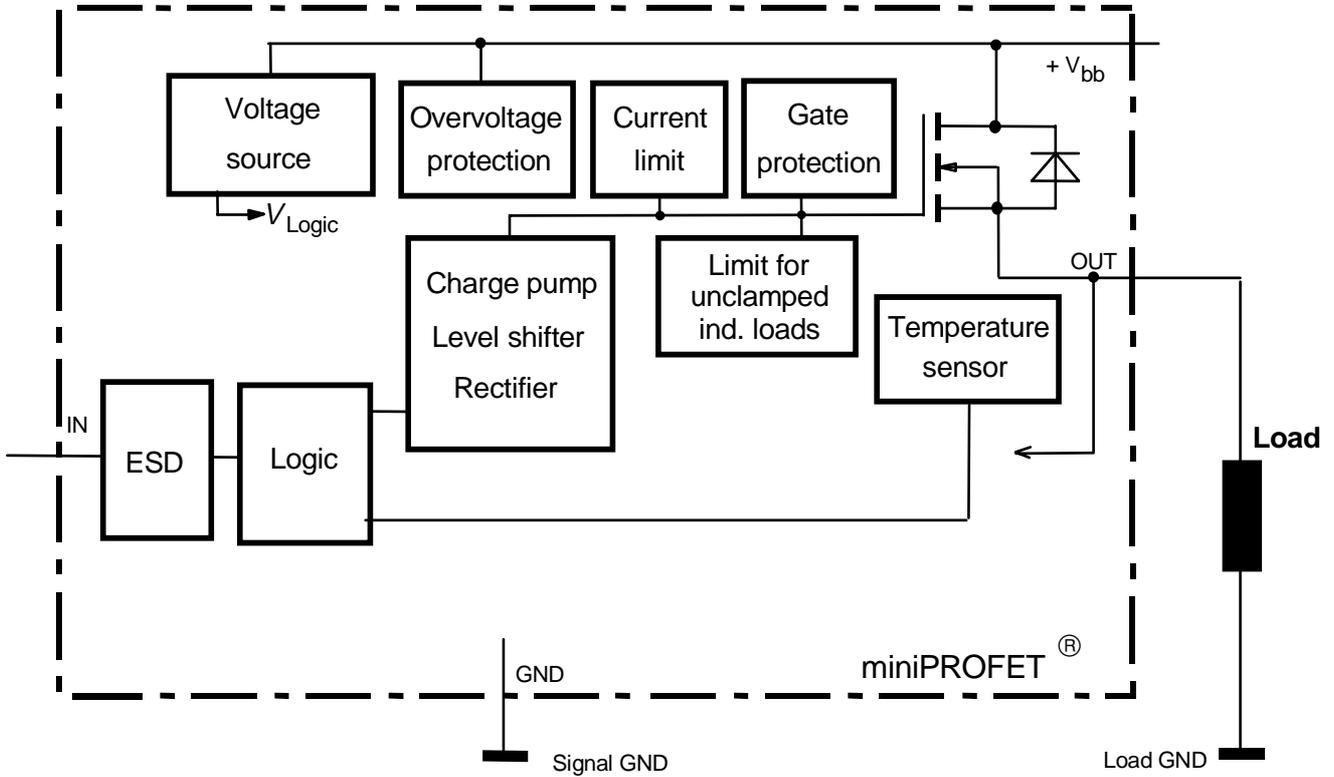
Application

- All types of resistive, inductive and capacitive loads
- μ C compatible power switch for 12 V, 24 V and 42 V DC applications
- Replaces electromechanical relays and discrete circuits

General Description

N channel vertical power FET with charge pump, ground referenced CMOS compatible input, monolithically integrated in Smart SIPMOS[®] technology. Fully protected by embedded protection functions.

Block Diagram



Pin	Symbol	Function
1	GND	Logic ground
2	IN	Input, activates the power switch in case of logic high signal
3	OUT	Output to the load
4	NC	not connected
5	Vbb	Positive power supply voltage
6	Vbb	Positive power supply voltage
7	Vbb	Positive power supply voltage
8	Vbb	Positive power supply voltage

Maximum Ratings at $T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value	Unit
Supply voltage	V_{bb}	52	V
Supply voltage for full short circuit protection	$V_{bb(SC)}$	50	
Continuous input voltage	V_{IN}	-10 ... +16	
Load current (Short - circuit current, see page 5)	I_L	self limited	A
Current through input pin (DC)	I_{IN}	± 5	mA
Operating temperature	T_j	-40 ... +150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 ... +150	
Power dissipation ¹⁾	P_{tot}	1.5	W
Inductive load switch-off energy dissipation ¹⁾²⁾ single pulse, (see page 8) $T_j = 150^\circ\text{C}$, $I_L = 1\text{ A}$	E_{AS}	125	mJ
Load dump protection ²⁾ $V_{LoadDump}^{3)} = V_A + V_S$ $R_I = 2\Omega$, $t_d = 400\text{ms}$, $V_{IN} = \text{low or high}$, $V_A = 13,5\text{V}$ $R_L = 13.5\ \Omega$ $R_L = 27\ \Omega$	$V_{Loaddump}$	73.5 83.5	V
Electrostatic discharge voltage (Human Body Model) according to ANSI EOS/ESD - S5.1 - 1993 ESD STM5.1 - 1998 Input pin all other pins	V_{ESD}	± 1 ± 5	kV

Thermal Characteristics

Thermal resistance @ min. footprint	$R_{th(JA)}$	-	95	-	K/W
Thermal resistance @ 6 cm ² cooling area ¹⁾	$R_{th(JA)}$	-	70	83	

¹ Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6 cm² (one layer, 70µm thick) copper area for drain connection. PCB is vertical without blown air. (see page 16)

²not tested, specified by design

³ $V_{Loaddump}$ is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839 .

Supply voltages higher than $V_{bb(AZ)}$ require an external current limit for the GND pin, e.g. with a 150Ω resistor in GND connection. A resistor for the protection of the input is integrated.

Electrical Characteristics

Parameter and Conditions at $T_j = -40\dots+150^\circ\text{C}$, $V_{bb} = 12..42\text{V}$, unless otherwise specified	Symbol	Values			Unit
		min.	typ.	max.	

Load Switching Capabilities and Characteristics

On-state resistance $T_j = 25^\circ\text{C}$, $I_L = 1\text{ A}$, $V_{bb} = 9\dots52\text{ V}$ $T_j = 150^\circ\text{C}$	R_{ON}	-	150	200	m Ω
		-	270	380	
Nominal load current; Device on PCB ¹⁾ $T_C = 85^\circ\text{C}$, $T_j \leq 150^\circ\text{C}$	$I_{L(nom)}$	1.3	1.7	-	A
Turn-on time to 90% V_{OUT} $R_L = 47\ \Omega$	t_{on}	-	80	180	μs
Turn-off time to 10% V_{OUT} $R_L = 47\ \Omega$	t_{off}	-	80	200	
Slew rate on 10 to 30% V_{OUT} , $R_L = 47\ \Omega$, $V_{bb} = 13.5\text{ V}$	dV/dt_{on}	-	0.7	2	V/ μs
Slew rate off 70 to 40% V_{OUT} , $R_L = 47\ \Omega$, $V_{bb} = 13.5\text{ V}$	$-dV/dt_{off}$	-	0.9	2	

Operating Parameters

Operating voltage	$V_{bb(on)}$	6	-	52	V
Undervoltage shutdown of charge pump $T_j = -40\dots+85^\circ\text{C}$ $T_j = 150^\circ\text{C}$	$V_{bb(under)}$	-	-	4	
		-	-	5.5	
Undervoltage restart of charge pump	$V_{bb(u\ cp)}$	-	4	5.5	
Standby current $T_j = -40\dots+85^\circ\text{C}$, $V_{IN} = \text{low}$ $T_j = +150^\circ\text{C}^2)$, $V_{IN} = \text{low}$	$I_{bb(off)}$	-	-	15	μA
		-	-	18	
Leakage output current (included in $I_{bb(off)}$) $V_{IN} = \text{low}$	$I_{L(off)}$	-	-	5	
Operating current $V_{IN} = \text{high}$	I_{GND}	-	0.8	2	mA

¹ Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6 cm² (one layer, 70 μm thick) copper area for drain connection. PCB is vertical without blown air. (see page 16)

² higher current due temperature sensor

Electrical Characteristics

Parameter and Conditions at $T_j = -40\dots+150^\circ\text{C}$, $V_{bb} = 12.42\text{V}$, unless otherwise specified	Symbol	Values			Unit
		min.	typ.	max.	

Protection Functions

Initial peak short circuit current limit (pin 5 to 3) $T_j = -40^\circ\text{C}$, $V_{bb} = 20\text{V}$, $t_m = 150\ \mu\text{s}$ $T_j = 25^\circ\text{C}$ $T_j = 150^\circ\text{C}$ $T_j = -40\dots+150^\circ\text{C}$, $V_{bb} > 40\text{V}$, (see page 11)	$I_{L(SCp)}$	-	-	9	A
		-	6.5	-	
		4	-	-	
		-	5 ¹⁾	-	
Repetitive short circuit current limit $T_j = T_{jt}$ (see timing diagrams) $V_{bb} < 40\text{V}$ $V_{bb} > 40\text{V}$	$I_{L(SCr)}$	-	6	-	
		-	4.5	-	
Output clamp (inductive load switch off) at $V_{OUT} = V_{bb} - V_{ON(CL)}$, $I_{bb} = 4\text{mA}$	$V_{ON(CL)}$	59	63	-	V
Overvoltage protection ²⁾ $I_{bb} = 4\text{mA}$	$V_{bb(AZ)}$	62	-	-	
Thermal overload trip temperature	T_{jt}	150	-	-	$^\circ\text{C}$
Thermal hysteresis	ΔT_{jt}	-	10	-	K

Reverse Battery

Reverse battery ³⁾	$-V_{bb}$	-	-	52	V
Drain-source diode voltage ($V_{OUT} > V_{bb}$) $T_j = 150^\circ\text{C}$	$-V_{ON}$	-	600	-	mV

¹not tested, specified by design

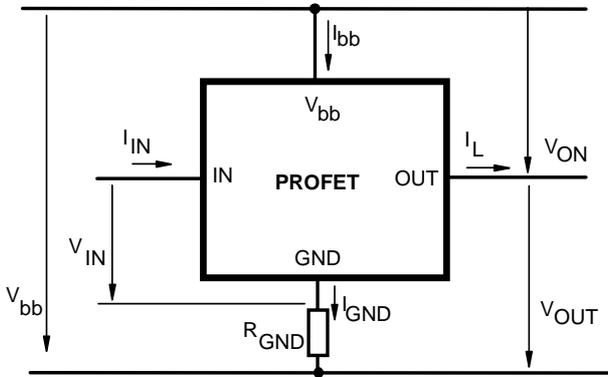
² see also $V_{ON(CL)}$ in circuit diagram on page 7

³Requires a $150\ \Omega$ resistor in GND connection. The reverse load current through the intrinsic drain-source diode has to be limited by the connected load. Power dissipation is higher compared to normal operating conditions due to the voltage drop across the drain-source diode. The temperature protection is not active during reverse current operation! Input current has to be limited (see max. ratings page 3).

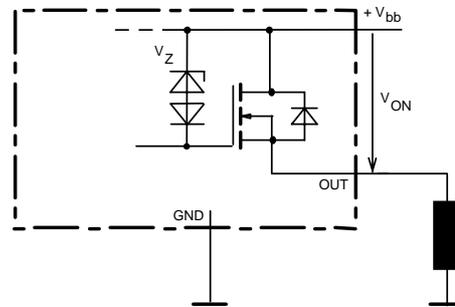
Electrical Characteristics

Parameter and Conditions at $T_j = -40...+150^{\circ}\text{C}$, $V_{bb} = 12..42\text{V}$, unless otherwise specified	Symbol	Values			Unit
		min.	typ.	max.	
Input					
Input turn-on threshold voltage	$V_{IN(T+)}$	-	-	2.2	V
Input turn-off threshold voltage	$V_{IN(T-)}$	0.8	-	-	
Input threshold hysteresis	$\Delta V_{IN(T)}$	-	0.4	-	
Off state input current $V_{IN} = 0.7\text{ V}$	$I_{IN(off)}$	1	-	25	μA
On state input current $V_{IN} = 5\text{ V}$	$I_{IN(on)}$	3	-	25	
Input resistance (see page 7)	R_I	2	3.5	5	$\text{k}\Omega$

Terms

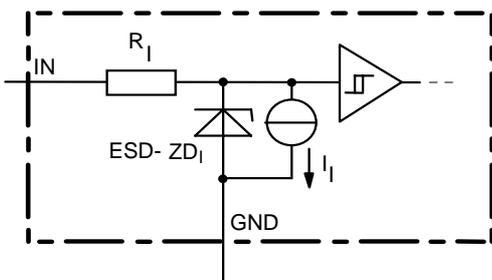


Inductive and overvoltage output clamp



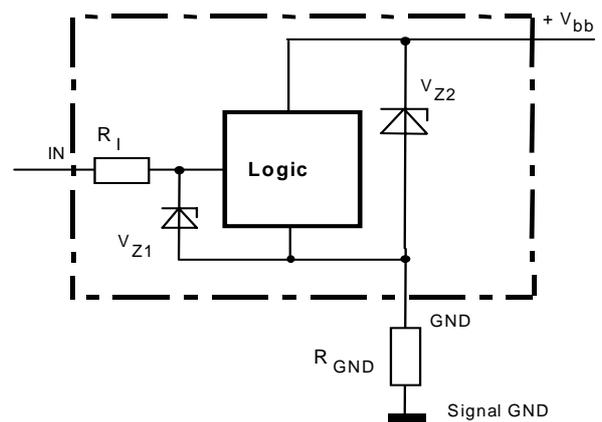
V_{ON} clamped to 59V min.

Input circuit (ESD protection)



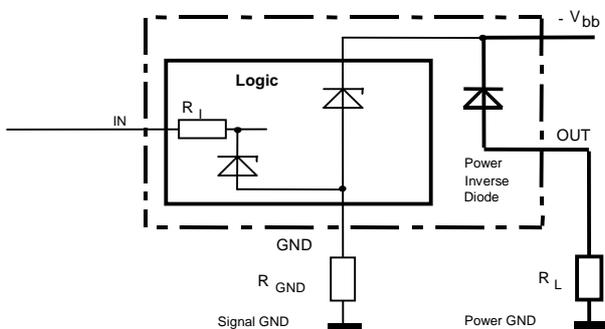
The use of ESD zener diodes as voltage clamp at DC conditions is not recommended

Overvoltage protection of logic part



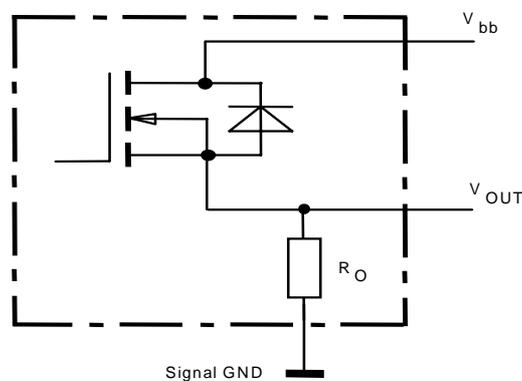
$V_{Z1}=6.1V$ typ., $V_{Z2}=V_{bb(AZ)}=62V$ min.,
 $R_I=3.5\text{ k}\Omega$ typ., $R_{GND}=150\Omega$

Reverse battery protection



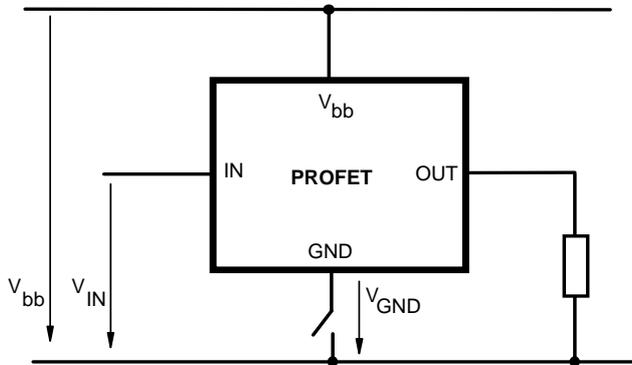
$R_{GND}=150\Omega$, $R_I=3.5\text{ k}\Omega$ typ.,
 Temperature protection is not active during inverse current

Internal output pull down

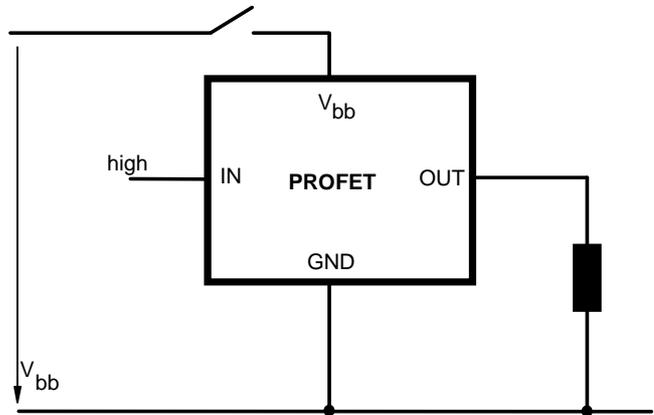


$R_O = 200\text{ k}\Omega$ typ.

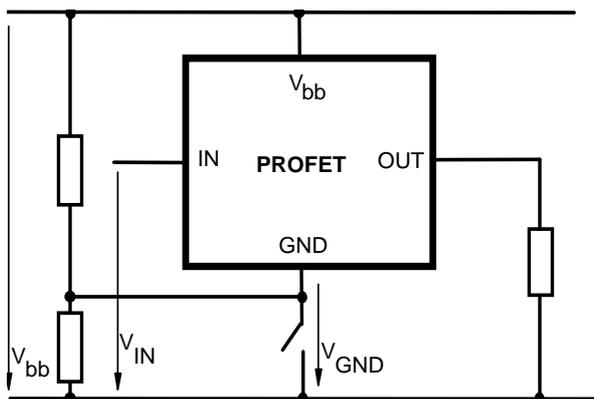
GND disconnect



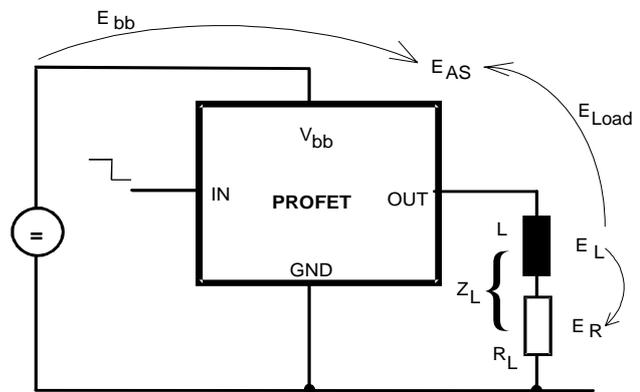
V_{bb} disconnect with charged inductive load



GND disconnect with GND pull up



Inductive Load switch-off energy dissipation



Energy stored in load inductance: $E_L = \frac{1}{2} * L * I_L^2$

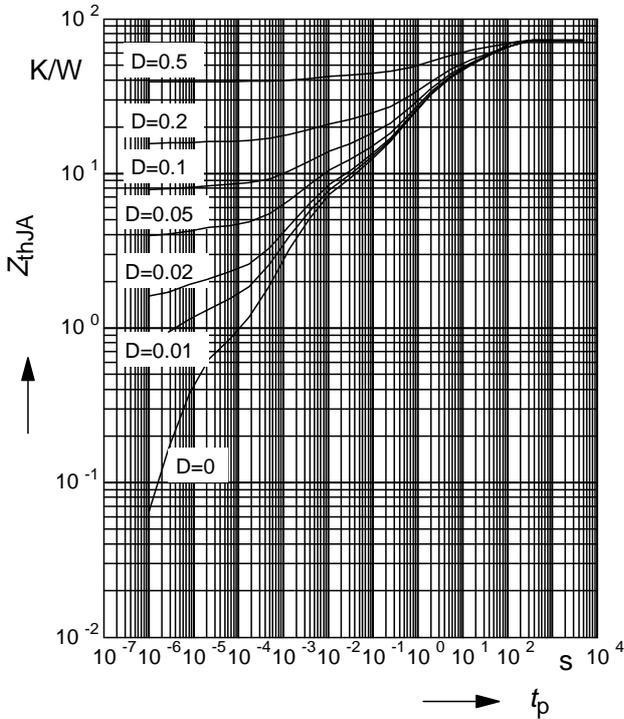
While demagnetizing load inductance, the energy dissipated in PROFET is $E_{AS} = E_{bb} + E_L - E_R = \int V_{ON(CL)} * i_L(t) dt$, with an approximate solution for $R_L > 0\Omega$:

$$E_{AS} = \frac{I_L * L}{2 * R_L} * (V_{bb} + |V_{OUT(CL)}|) * \ln\left(1 + \frac{I_L * R_L}{|V_{OUT(CL)}|}\right)$$

Typ. transient thermal impedance

$Z_{thJA} = f(t_p)$ @ 6cm² heatsink area

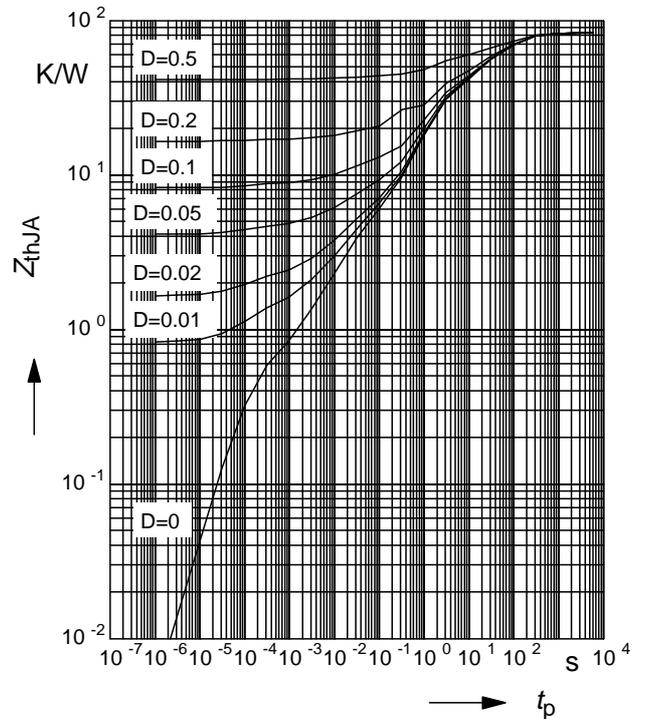
Parameter: $D = t_p / T$



Typ. transient thermal impedance

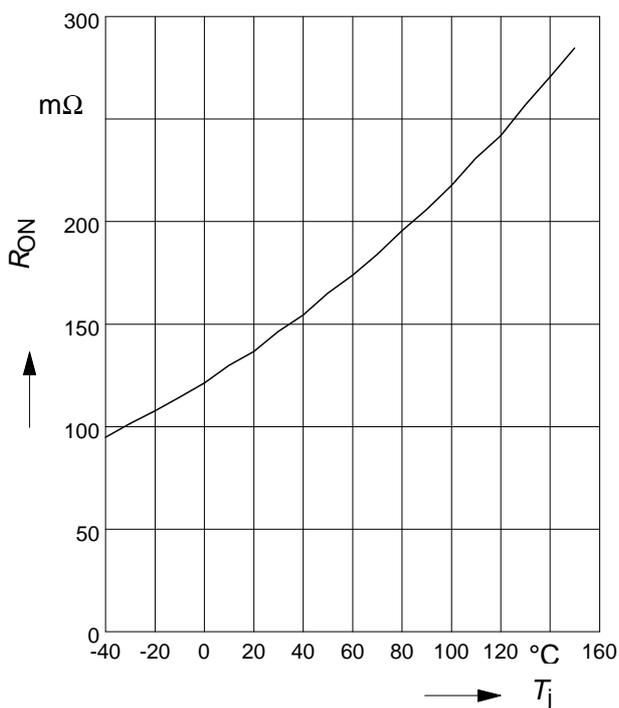
$Z_{thJC} = f(t_p)$ @ min. footprint

Parameter: $D = t_p / T$



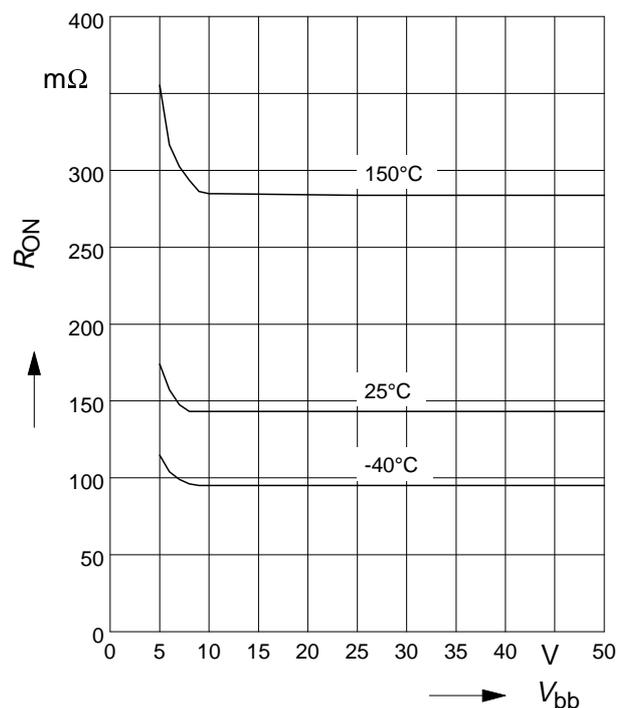
Typ. on-state resistance

$R_{ON} = f(T_j)$; $V_{bb} = 13,5V$; $V_{in} = \text{high}$



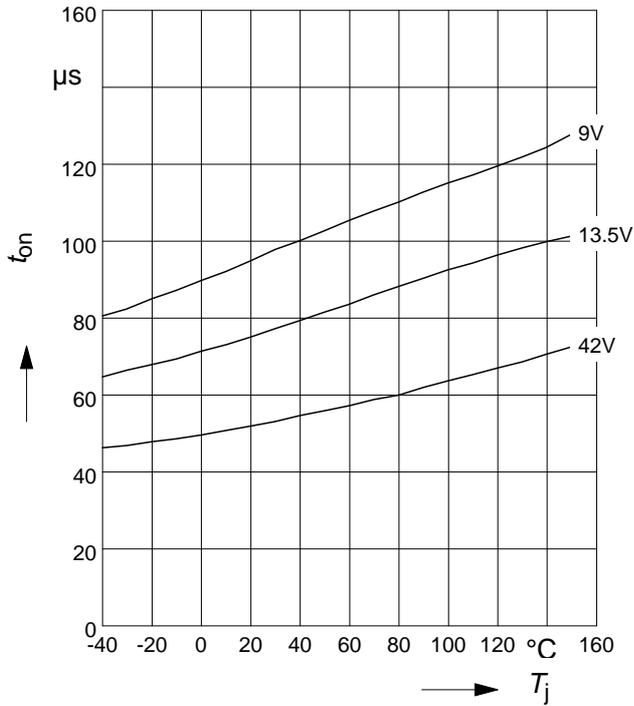
Typ. on-state resistance

$R_{ON} = f(V_{bb})$; $I_L = 1 A$; $V_{in} = \text{high}$



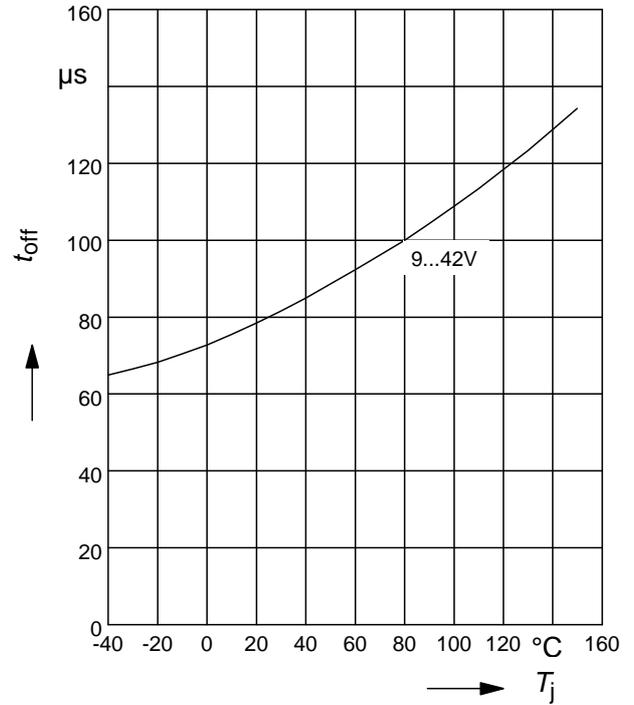
Typ. turn on time

$t_{on} = f(T_j); R_L = 47\Omega$



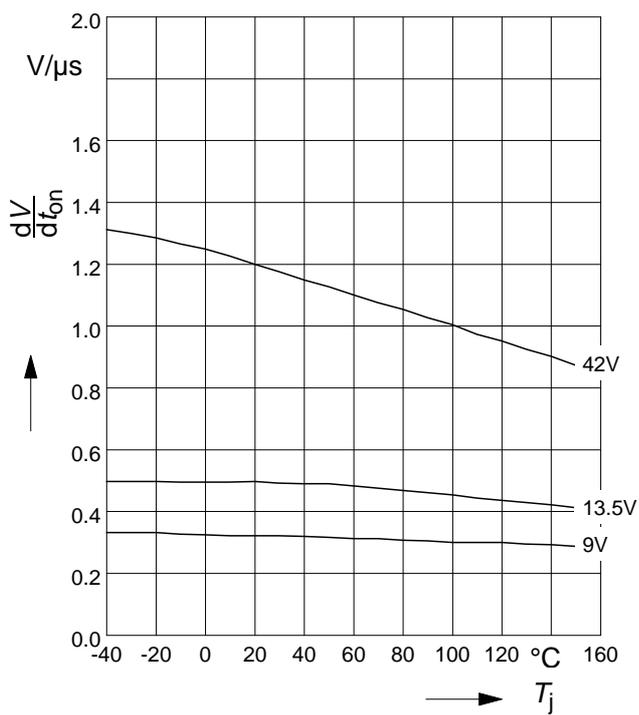
Typ. turn off time

$t_{off} = f(T_j); R_L = 47\Omega$



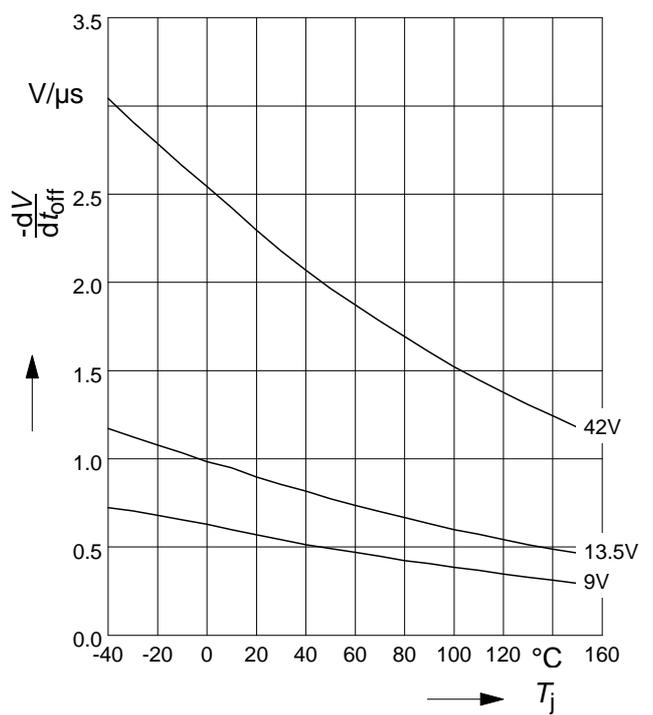
Typ. slew rate on

$dV/dt_{on} = f(T_j); R_L = 47\Omega$



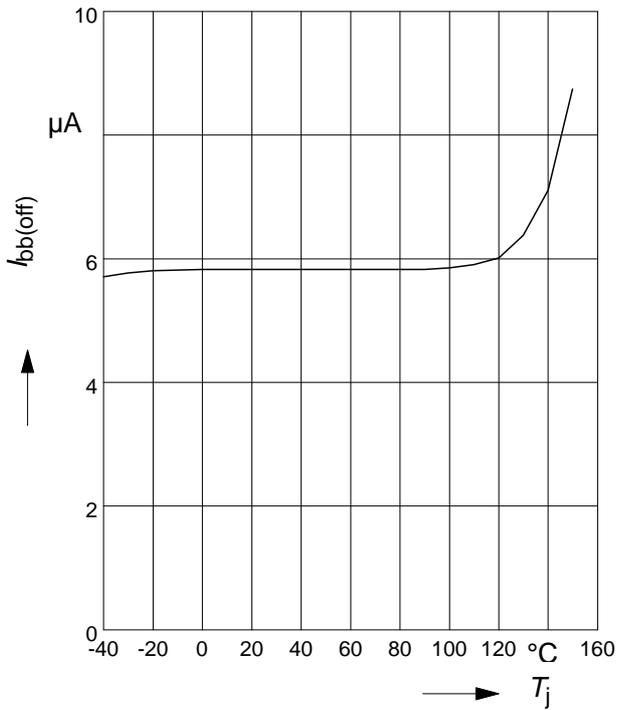
Typ. slew rate off

$dV/dt_{off} = f(T_j); R_L = 47\Omega$



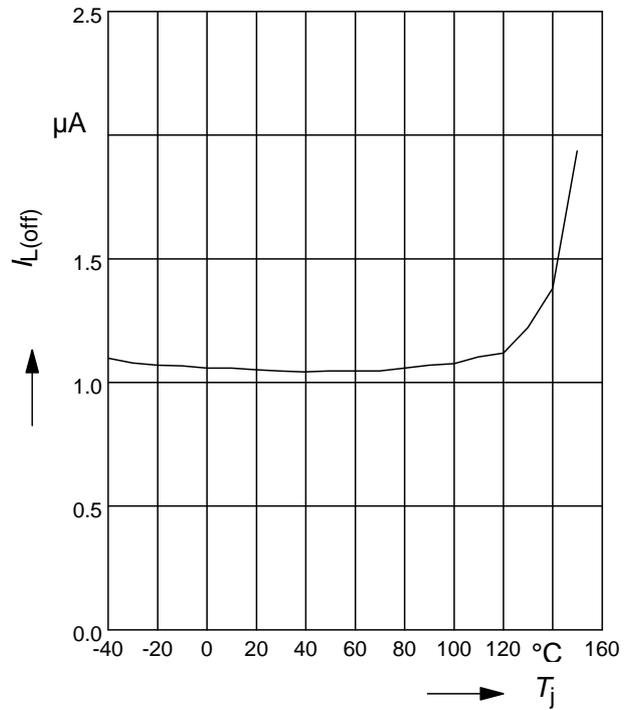
Typ. standby current

$I_{bb(off)} = f(T_j)$; $V_{bb} = 42V$; $V_{IN} = low$



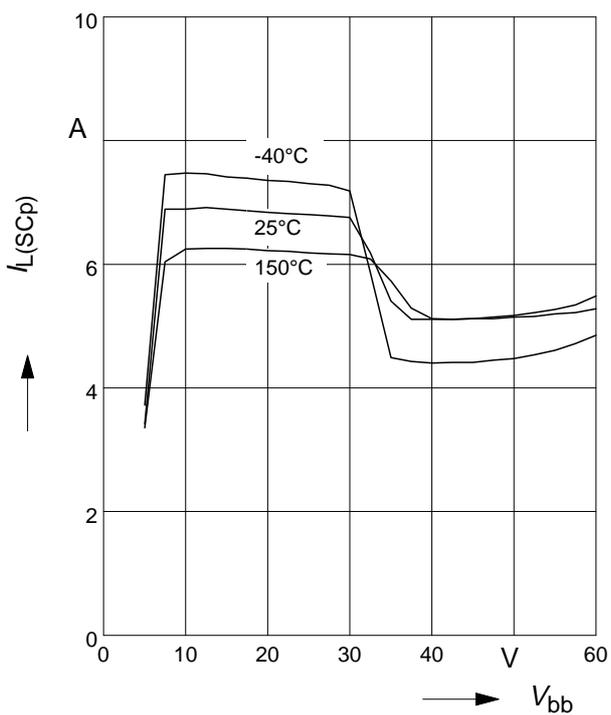
Typ. leakage current

$I_{L(off)} = f(T_j)$; $V_{bb} = 42V$; $V_{IN} = low$



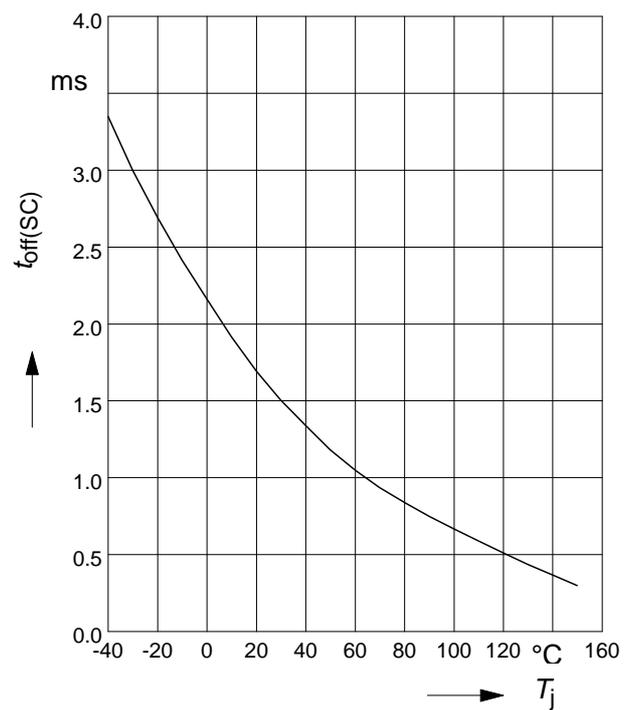
Typ. initial peak short circuit current limit

$I_{L(SCp)} = f(V_{bb})$



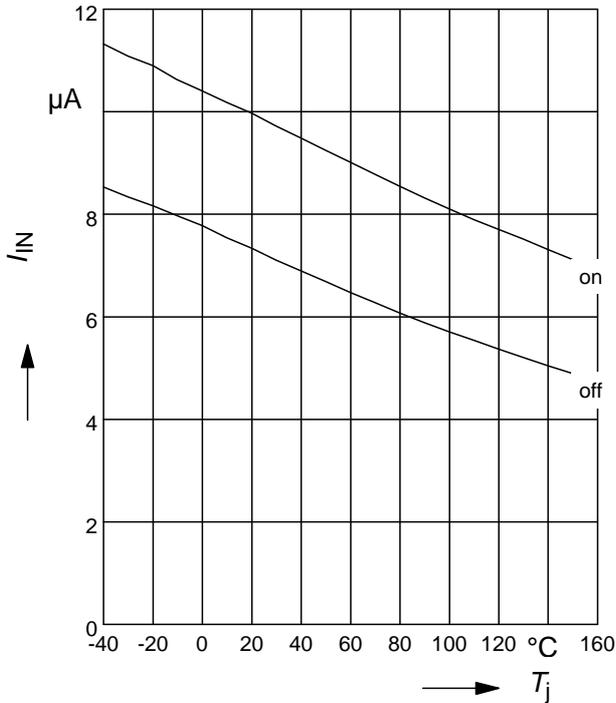
Typ. initial short circuit shutdown time

$t_{off(SC)} = f(T_{j,start})$; $V_{bb} = 20V$



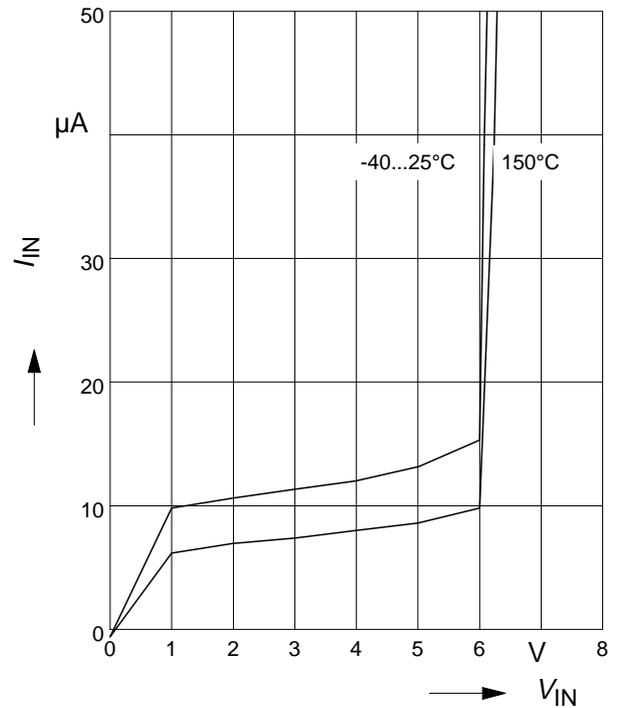
Typ. input current

$I_{IN(on/off)} = f(T_j)$; $V_{bb} = 13,5V$; $V_{IN} = \text{low/high}$
 $V_{INlow} \leq 0,7V$; $V_{INhigh} = 5V$



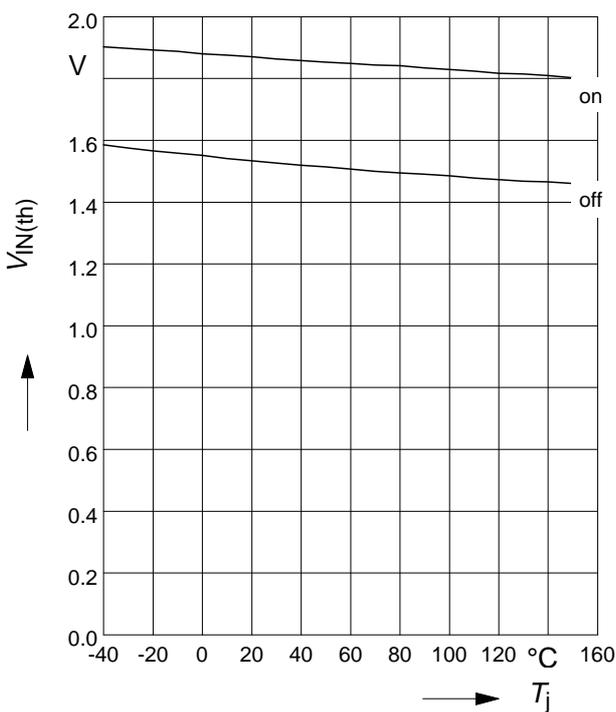
Typ. input current

$I_{IN} = f(V_{IN})$; $V_{bb} = 13.5V$



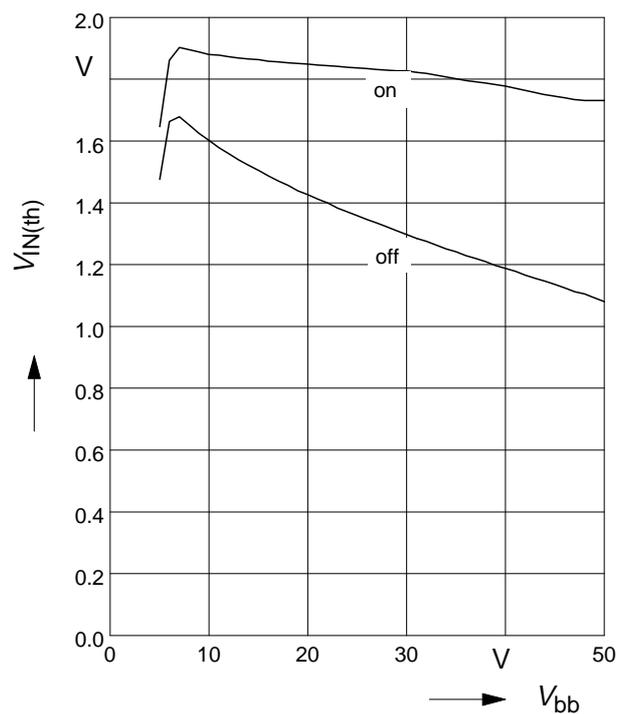
Typ. input threshold voltage

$V_{IN(th)} = f(T_j)$; $V_{bb} = 13,5V$



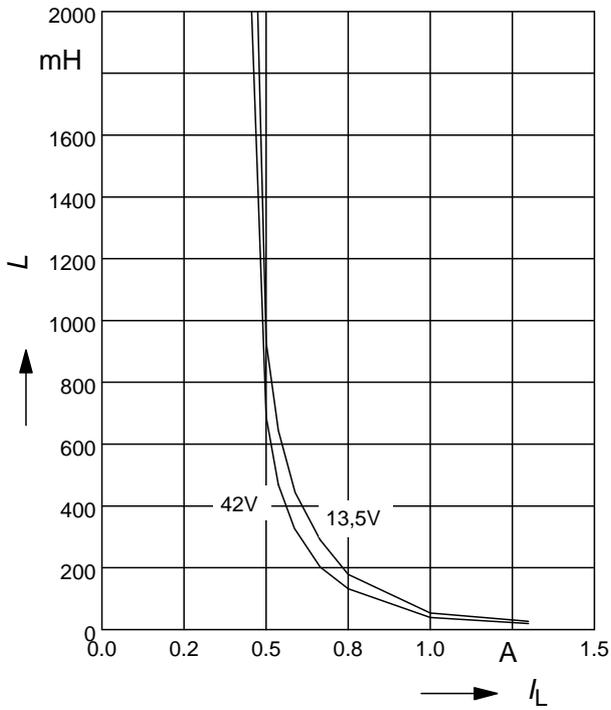
Typ. input threshold voltage

$V_{IN(th)} = f(V_{bb})$; $T_j = 25^{\circ}C$



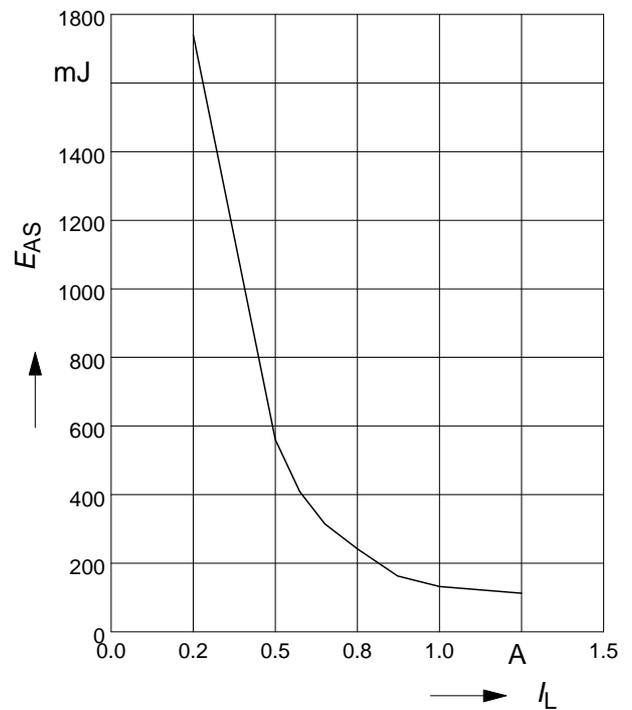
Maximum allowable load inductance for a single switch off

$L = f(I_L); T_{jstart}=150^{\circ}\text{C}, R_L=0\Omega$



Maximum allowable inductive switch-off energy, single pulse

$E_{AS} = f(I_L); T_{jstart} = 150^{\circ}\text{C}, V_{bb} = 13,5\text{V}$



Timing diagrams

Figure 1a: V_{bb} turn on:

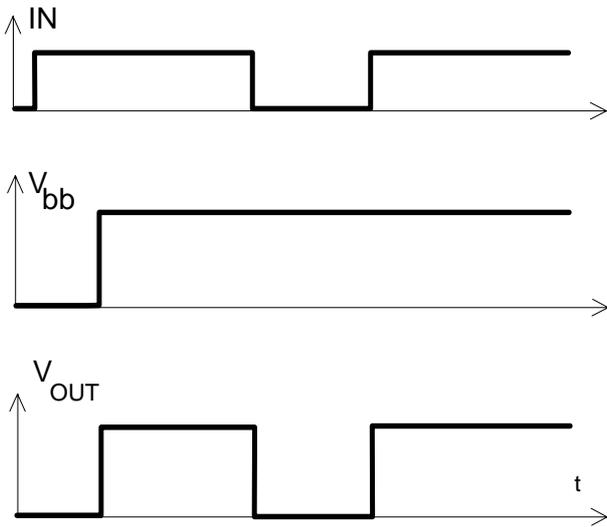


Figure 2b: Switching a lamp,

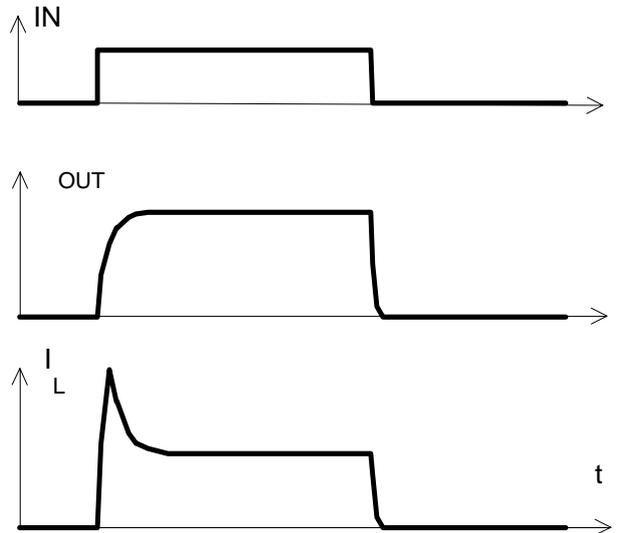


Figure 2a: Switching a resistive load, turn-on/off time and slew rate definition

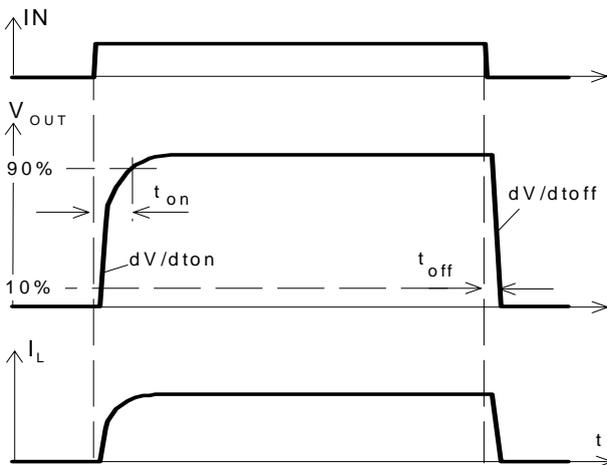


Figure 2c: Switching an inductive load

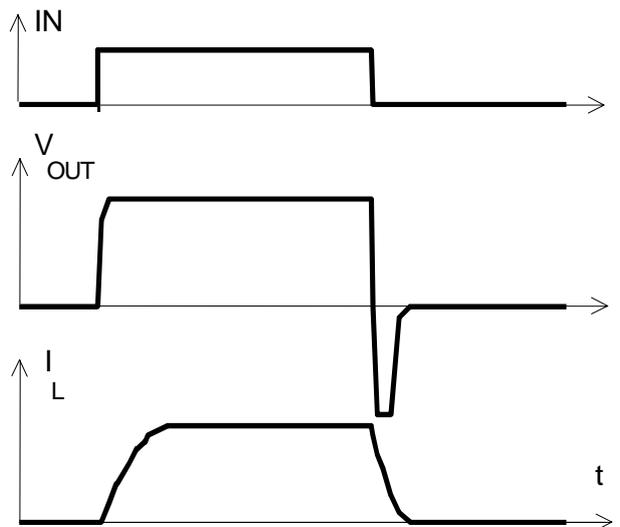
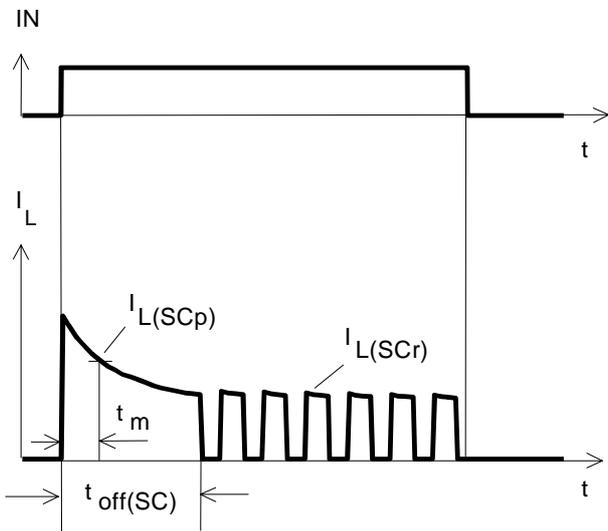


Figure 3a: Turn on into short circuit, shut down by overtemperature, restart by cooling



Heating up of the chip may require several milliseconds, depending on external conditions.

Figure 4: Overtemperature: Reset if $T_j < T_{jt}$

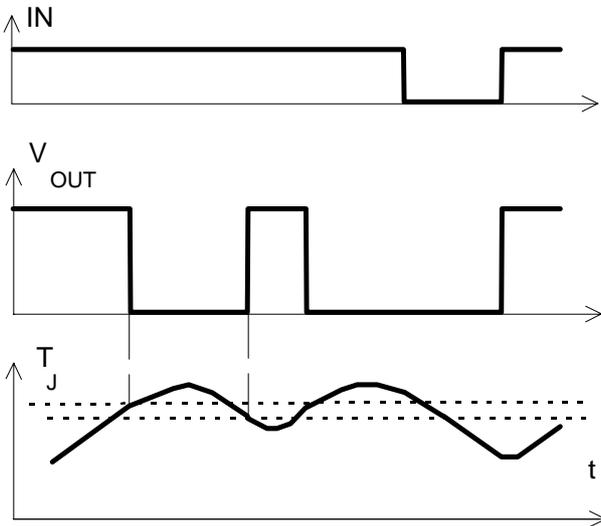
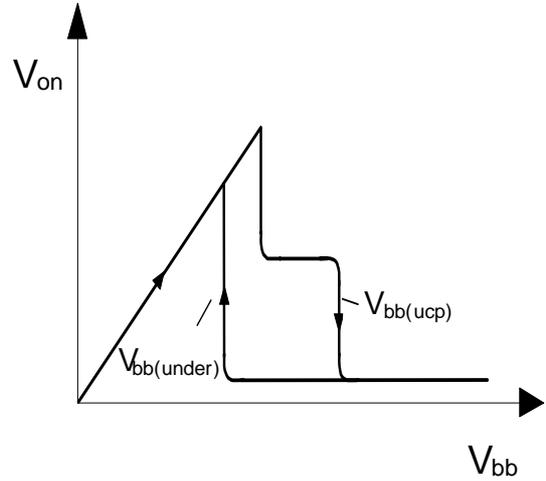


Figure 5: Undervoltage restart of charge pump

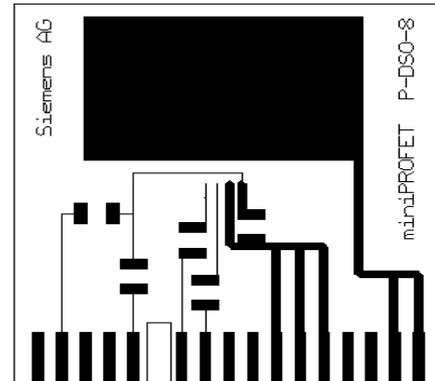
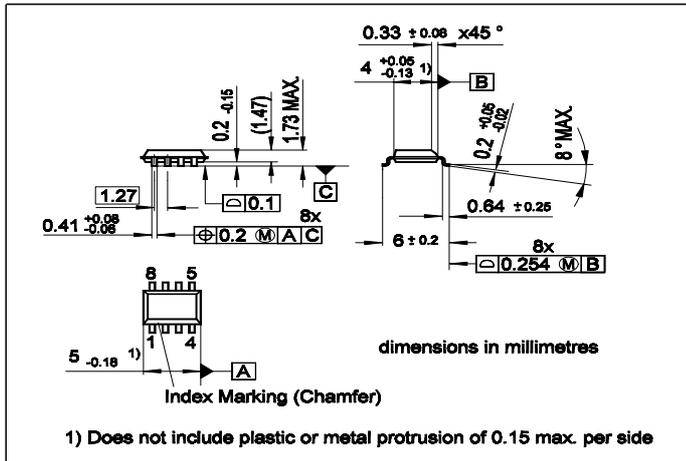


Package and ordering code

all dimensions in mm

Ordering code:

Q67060-S7307



Printed circuit board (FR4, 1.5mm thick, one layer 70 μ m, 6cm² active heatsink area) as a reference for max. power dissipation P_{tot} nominal load current $I_{L(nom)}$ and thermal resistance R_{thja}

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